NSN 5962-01-077-0391

Memory Microcircuit - Page 1 of 2



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Body Length:	
0.440 inches	
Body Width:	
Between 0.248 inches and 0.325 inches	
Body Height:	
0.085 inches	
Maximum Power Dissipation Rating:	
500.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees fahrenheit	
Features Provided:	
Hermetically sealed and monolithic and high speed and programmable and schottky and bipolar and w/storage and 3-state	output and
w/decoded output and expandable	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Flat pack	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
40.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, hig	h to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
82577-932623 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

Yes - demil/mli

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Memory Microcircuit - Page 2 of 2

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